



#14/Amend. CNE
3A/3/03
JQ

RESPONSE UNDER 37 C.F.R. § 1.116 EXPEDITED
PROCEDURE - EXAMINING GROUP 2815

Attorney Docket No. 5347-208

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Lucovsky et al. Examiner: A. Wilson
Serial No.: 09/891,552 Group Art Unit: 2815
Filed: June 25, 2001
For: NOVEL NON-CRYSTALLINE OXIDES FOR USE IN MICROELECTRONIC,
OPTICAL, AND OTHER APPLICATIONS

March 5, 2003.

Box AF
Commissioner for Patents
Washington, DC 20231

RECEIVED
MAR 11 2003
1C 2800 MAIL ROOM

AMENDMENT AFTER FINAL

Sir:

This Amendment After Final is responsive to the final Office Action dated January 7, 2003. Applicants respectfully request entry of this Amendment After Final and allowance of the present application. Alternatively, Applicants respectfully request entry of this Amendment as narrowing the issues for further consideration. A "Version with Marking to Show Changes Made" is attached.

In the Claims:

Please replace claim 2 with the following amended claim.

2. (Amended) The oxide according to Claim 1, wherein A is aluminum (Al), B is tantalum (Ta), M is hafnium (Hf) or zirconium (Zr), n is 1, m is 2, and x is less than 0.25.

Please replace claim 14 with the following amended claim.

14. (Amended) The field effect transistor according to Claim 11, wherein A is aluminum (Al), B is tantalum (Ta), M is hafnium (Hf) or zirconium (Zr), n is 1, m is 2, and x is less than 0.25.